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## Structural evolution and bonding features of electron deficient copper chalcogenides

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A group of otherwise covalent ternary copper sulfides and selenides demonstrate metallic p-type conductivity and Pauli paramagnetism, which distinguishes them from semiconducting counterparts built up from the same elements. This difference originates from the electron deficiency delocalized over structural units of copper chalcogenides. Considering the significant technological importance of chalcogenide materials, we surveyed ternary copper sulfides and selenides with alkali and alkaline earth cations to provide insights into their crystal structures and transport properties. We found that the compositions and structures of many chalcogenides can be rationalized based on two 2D nets with honeycomb and square lattice net topologies, respectively. We have also shown how simple electron-orbital counts can be applied to metallic chalcogenides with formally charge unbalanced compositions and demonstrated that these compounds are indeed electron deficient. In agreement with experimental data and DFT calculations, such phases demonstrate metallic p-type conductivity.

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### Introduction

Electron-deficient covalent materials combine directional bonding and low coordination numbers typical for covalent phases with metallic type conductivity. These materials can be described by the term “covalent metals” that summarizes their structural and physical properties. The “covalent” part reflects on the nature of chemical bonding and local structure (*i.e.*, a small difference in electronegativities), while the “metal” highlights the low electrical resistivity of the materials due to electron delocalization and deficiency. One common example of a compound with metallic properties and electronic delocalization is graphite, which is built of layers of covalently bonded carbon atoms with trigonal planar coordination and exhibits strong electron delocalization due to half-occupied bands with  $p_z$  character. Although strong electron delocalization is usually associated with bonds between elements that have a small electronegativity difference,  $\Delta\chi$ , some chalcogenide compounds exhibit a significant electron delocalization in the presence of a relatively large  $\Delta\chi$ . One such example is copper sulfides and selenides, which structures show features of covalently bound materials (low coordination numbers for copper and well-defined geometry of the Cu coordination polyhedra), while demonstrating metallic conductivity.

Numerous natural and synthetic copper chalcogenides with metallic conductivity and Pauli paramagnetism have

been known for decades.<sup>1–4</sup> Unlike graphite, materials such as covellite CuS, klockmannite CuSe, or umangite Cu<sub>3</sub>Se<sub>2</sub>, are p-type conductors. While the physical properties of many chalcogenides have been thoroughly studied, the theoretical basis of their physical behavior has been developed afterwards. The common trait of these phases is a deviation from the oxidation state formalism. It became widely acknowledged that the oxidation state of Cu in these peculiar phases is +1, while mixed +1/+2 states were ruled out,<sup>5–8</sup> resulting in the deficit of the formal negative charge in binary (CuS, CuSe, Cu<sub>3</sub>Se<sub>2</sub>, CuS<sub>2</sub>, CuSe<sub>2</sub>) and ternary (NaCu<sub>4</sub>S<sub>3</sub>, NaCu<sub>4</sub>Se<sub>3</sub>, NaCu<sub>4</sub>S<sub>4</sub>, NaCu<sub>4</sub>Se<sub>4</sub>) phases. This distinguishes copper from other metals, demonstrating truly mixed oxidation states in chalcogenides.<sup>9,10</sup> DFT study of covellite confirmed the presence of holes in the valence band and the absence of a bandgap in CuS (more precisely Cu<sub>6</sub>S<sub>6</sub>, as the structure is built on stacking of CuS and Cu<sub>2</sub>S<sub>2</sub> layers and has S–S bonds), and thus, the observed p-type metallic conductivity aligned perfectly with the experiments.<sup>11</sup> The holes originate from a mismatch between the number of molecular orbitals and the number of available valence electrons to fill them. The same study showed a significant level of hybridization between copper and sulfur valence orbitals near the Fermi level, indicating the delocalization of holes over Cu<sub>3</sub>S<sub>3</sub> building blocks in the covellite structure. The delocalization of holes over copper chalcogenide slabs (hereinafter, slab is defined as a layer made by connecting the simplest layers) suggests slightly higher positive charges on both copper and chalcogenide atoms (in other words, more positive on copper, less negative on sulfur), which must

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## Highlight

not be confused with mixed valence on both copper and chalcogen atoms.<sup>12</sup> The same phenomenon was confirmed in the recently reported paramagnetic  $\text{NaCu}_4\text{S}_3$  phase<sup>13</sup> and a series of related electron deficient phases.<sup>14–16</sup>

The unique electronic structure of covalent metals made them attractive for applications as a new class of catalyst for  $\text{CO}_2$  conversion into value-added products.<sup>17</sup> Apart from catalysis, metal chalcogenides were studied as prospective materials for a wide range of vital applications, including rechargeable batteries,<sup>18–27</sup> thermoelectric power generation,<sup>28–35</sup> heterogeneous photo- and electrocatalysis,<sup>36–39</sup> photovoltaics,<sup>40,41</sup> solar cells with unmatched performance,<sup>42–46</sup> radionuclides removal,<sup>47</sup> neuromorphic engineering,<sup>48,49</sup> cancer treatment,<sup>50,51</sup> and others.<sup>52,53</sup> Although most chalcogenide research focuses on the semiconductors, recent advances in understanding the electronic behavior of materials with an intermediate type of bonding challenged the traditional systematics of covalent/metallic/ionic bonding mechanisms.<sup>54–56</sup> This intermediate type of bonding, which has also been termed “metavalent”, is responsible for unconventional properties of materials such as  $\text{GeTe}$ ,  $\text{SnTe}$ , and  $\text{PbTe}$ ,<sup>54–56</sup> which have promising applications in thermoelectrics. Although these materials started attracting more interest, a detailed understanding of their electronic structures and crystal design principles is still missing.

The goal of this highlight is to illustrate electron deficiency in metallic covalent compounds by using the structural and electronic features of ternary copper sulfides and selenides with alkali and alkaline metals as an example. These materials are divided into two major groups: formally charge balanced and formally charge unbalanced (*i.e.* electron deficient). A common and most apparent indication of a potential chalcogenide covalent metal is the difficulty of assigning oxidation states in the composition using the common oxidation states formalism, which provides a starting point for their systematic analysis. Following a traditional crystallographic approach, we start with the local coordination of copper and chalcogenide atoms and consider building blocks in the structures to show how they can be arranged in more complex structures. While many hypothetical building unit stackings are possible, few of them have been realized in real materials, leaving this field awaiting the synthesis of many new compositions.

## Synthesis of copper chalcogenides

Before discussing the electronic and structural properties of chalcogenide materials, we first briefly describe the synthetic methods for their preparation (Fig. 1). Ternary copper sulfides and selenides are very commonly synthesized by employing alkali polychalcogenide fluxes.<sup>57</sup> We use the term “flux” here to highlight the excess of polychalcogenide reagents compared to the stoichiometry of a product and the subsequent necessity of flux removal after reaction completion. Alkali polychalcogenide fluxes offer numerous



Fig. 1 Three main routes to the synthesis of copper chalcogenides.

advantages, including compositional versatility and low melting temperatures.<sup>16,58–63</sup> The major drawback of these compounds is high moisture sensitivity, as well as challenges associated with the tedious synthesis of these starting materials by reacting alkali metals with chalcogens in liquid ammonia. However, this disadvantage can be overcome by using metal chalcogenides ( $\text{Na}_2\text{Q}$ ,  $\text{K}_2\text{Q}$ , *etc.*,  $\text{Q} = \text{S}$  or  $\text{Se}$ ) in combination with the respective chalcogens to generate polychalcogenide fluxes *in situ*. Copper can be introduced in the reaction in the elemental form or as a pre-made binary chalcogenide. Copper(II) oxide, used for the preparation of  $\text{NaCu}_4\text{Se}_4$  phase is a rather unusual starting material.<sup>16</sup> In most cases, the reagents are typically mixed in an inert atmosphere and sealed in a glass ampoule (quartz or Pyrex, depending on reaction temperatures) under vacuum, then melted and slowly cooled for crystallization. To melt and react the starting materials, a wide temperature range of 350–1100 °C is employed.<sup>16,58–63</sup> Excess flux is removed by washing the reaction products with DI water and organic solvents, typically DMF. Some sulfides were synthesized using binary precursors combined with elemental sulfur in exact stoichiometric ratios to target certain compositions.<sup>58,64,65</sup> Overall, this approach employs the same apparatus as flux reactions (*i.e.*, slow cooling of reactions in sealed tubes).

Besides polychalcogenides, other sources of alkali cations, including carbonates, thiocyanates, and hydroxide–halide mixtures, can be employed to create fluxes. To avoid pressure buildup during the synthesis, reactions with carbonates are performed in open crucibles under an inert atmosphere.<sup>14,66–71</sup> Mixed alkali hydroxides–sodium iodide flux was successfully employed for the synthesis of charge unbalanced  $\text{Na}_3\text{Cu}_4\text{Se}_4$  phase isostructural with  $\text{K}_3\text{Cu}_4\text{Se}_4$ .<sup>72</sup> Such flux, however, is highly reactive and cannot be used for synthesis in a glass ampule or alumina crucible. Therefore, preparations of  $\text{Na}_3\text{Cu}_4\text{Se}_4$  and some other phases were done in a glassy carbon boat under nitrogen flow in a tube furnace.<sup>72</sup> Thiocyanate fluxes were used to prepare  $\text{BaCu}_2\text{S}_2$  and  $\text{CsCu}_5\text{S}_3$  phases in two-step processes.<sup>73,74</sup> Potassium thiocyanate, used for the synthesis of Ba phase, acted more like a solvent, as the resulting structure does not contain potassium. On the contrary, the synthesis of  $\text{CsCu}_5\text{S}_3$  was assisted by cesium thiocyanate flux.



Although, in most cases reported so far, elemental starting materials are used as primary reagents, one can employ boron–chalcogen mixtures (BCM) to reduce oxides and form chalcogenide phases. This method is generally utilized for the synthesis of copper chalcogenides with elements that have high oxygen affinity and, thus, tend to oxidize in air. For example, NaCuUS<sub>3</sub> phase can be formed by reacting U<sub>3</sub>O<sub>8</sub>, Cu, Na<sub>2</sub>CO<sub>3</sub>, B, and S.<sup>75</sup> In this reaction, B binds oxygen in the system and S reacts with the metals, providing both metal chalcogenides to form the final phase and the polychalcogenide flux, NaS<sub>n</sub>, to grow its single crystals. Similarly, the CsCu<sub>4</sub>Q<sub>3</sub> phase has been prepared using BCM.<sup>76</sup> Unlike the previous report on the synthesis of CsCu<sub>4</sub>-S<sub>3</sub> phase, where the reaction was performed under an Ar atmosphere,<sup>70</sup> the BCM reaction was performed in a sealed silica tube. Alternatively, the CsCu<sub>4</sub>Se<sub>3</sub> phase can be obtained by using a hydrothermal route, which is relatively less common for chalcogenides.<sup>77</sup> This phase formed in the reaction between ≈250 mg of a mixture of K<sub>2</sub>Se<sub>4</sub>, Cu, and CsCl in a sealed quartz ampoule with 0.5 ml of DI water at 120 and 170 °C.<sup>77</sup> These examples show interchangeability between the synthetic techniques. Additionally, new phases can be obtained by solid state postsynthetic modifications of the known phases. For example, a rare case of utilizing ternary sulfide as a starting material was the preparation of the CsCu<sub>5</sub>S<sub>3</sub> phase *via* solid state reaction of the CsCu<sub>4</sub>S<sub>3</sub> phase with extra copper.<sup>78</sup> Overall, rich variability of synthetic techniques offers a convenient playground for the synthesis of new copper chalcogenide phases with desired compositions and properties.

Naturally, the formation of solid solutions between isostructural sulfides and selenides can be assumed. As a recent report on this matter demonstrated, the mismatches of chalcogenide sizes and covalency result in the pronounced structural ordering in mixed chalcogenides.<sup>79</sup> This ordering was rationalized based on crystallographic data and hard–soft acid–base principles, which allows for the avoidance of costly DFT calculations. The results were confirmed experimentally,

and the new KCuZrTe<sub>2</sub>S ordered mixed anionic phase was prepared.

## Copper chalcogenides building blocks and the electron count

In the structures of binary and ternary chalcogenides, copper atoms coordinate two to four Q atoms (Table 1), with the most common coordination numbers being 3 and 4, corresponding to trigonal planar and tetrahedral coordination, respectively (Fig. 2). By sharing Q atoms, CuQ<sub>n</sub> units form discrete 0D ions, infinite 1D chains, 2D layers and slabs, or 3D frameworks. The reduction of structural dimensionality is commonly caused by additional cations, which divide copper chalcogenide units, and can be employed to decrease the thermal conductivity of materials.<sup>80,81</sup> Some structures of layered and quasi-layered chalcogenides can be described with two common 2D motifs. From the point of view of the structural topology, they are variations of honeycomb (**hcb**) and square lattice (**sql**) nets, with trigonally coordinated copper atoms predominantly forming basic **hcb** nets and tetrahedrally coordinated copper atoms – **sql** ones (Fig. 2). Both types of nets have the same CuQ stoichiometry of a basic single net; however, the formation of more complex structures through node connecting and sharing results in a variety of compositions in sulfides and selenides.

Basic single CuQ nets can be found in charge balanced A<sup>+</sup>-CuSe phases (A<sup>+</sup> = Li–K). The tetragonal structures of LiCuSe and NaCuSe phases are built of **sql** nets, whereas the hexagonal KCuSe is comprised of **hcb** nets (Fig. 2, Table 1). By doubling the basic structural units, one can derive the structures with [Cu<sub>2</sub>Q<sub>2</sub>]<sup>n-</sup> stoichiometries. Depending on the counter cation (either alkali or alkaline earth metal), these compounds can represent either charge balanced (such as BaCu<sub>2</sub>Q<sub>2</sub> series) or charge unbalanced compositions (for example, orthorhombic KCu<sub>2</sub>Se<sub>2</sub> phase). Nevertheless, both examples feature isolated **sql** nets separated by the cations. Multiplying of the layers can also occur by connecting atoms

**Table 1** Ternary copper chalcogenides with **sql** and **hcb** motifs in the structures

Composition	Orbital count	Electron count	Electron-orbital mismatch	Type	<b>sql</b> phases	<b>hcb</b> phases
A <sup>+</sup> (CuQ) <sup>-</sup>	18/2	17 + 1	0	<b>A(CuQ)<sub>n</sub>, n = 1</b>		
				Balanced	LiCuSe (ref. 82), NaCuSe (ref. 83)	KCuSe (ref. 83)
A <sup>+</sup> (Cu <sub>2</sub> Q <sub>2</sub> ) <sup>-</sup>	36/2	34 + 1	1	<b>n = 2</b>		
				Unbalanced	KCu <sub>2</sub> Se <sub>2</sub> (ref. 84)	—
A <sup>2+</sup> (Cu <sub>2</sub> Q <sub>2</sub> ) <sup>2-</sup>	36/2	34 + 2	0	Balanced	t-BaCu <sub>2</sub> Q <sub>2</sub> (ref. 73)	CaCu <sub>2</sub> S <sub>2</sub> (ref. 85)
A <sup>+</sup> (Cu <sub>3</sub> Q <sub>3</sub> ) <sup>-</sup>	54/2	51 + 1	2	<b>n = 3</b>		
				Unbalanced	Likely unstable	—
A <sup>2+</sup> (Cu <sub>3</sub> Q <sub>3</sub> ) <sup>2-</sup>	54/2	51 + 2	1	Unbalanced	—	—
A <sup>+</sup> (Cu <sub>4</sub> Q <sub>4</sub> ) <sup>-</sup>	72/2	68 + 1	3	<b>n = 4</b>		
				Unbalanced	Likely unstable	—
A <sup>2+</sup> (Cu <sub>4</sub> Q <sub>4</sub> ) <sup>2-</sup>	72/2	68 + 2	2	Unbalanced	Likely unstable	—
A <sup>+</sup> (Cu <sub>4</sub> Q <sub>2</sub> (Q <sub>2</sub> )) <sup>-</sup>	70/2	68 + 1	1	Unbalanced	—	NaCu <sub>4</sub> Q <sub>4</sub> (ref. 16 and 63)
A <sup>+</sup> (Cu <sub>4</sub> Q <sub>3</sub> ) <sup>-</sup>	64/2	62 + 1	1	<b>n = 5</b>		
				Unbalanced	ACu <sub>4</sub> Q <sub>3</sub> (ref. 60, 71, 76 and 86)	NaCu <sub>4</sub> Q <sub>3</sub> (ref. 13 and 15)
A <sup>+</sup> (Cu <sub>6</sub> Q <sub>4</sub> ) <sup>-</sup>	92/2	90 + 1	1	Unbalanced	—	NaCu <sub>6</sub> Se <sub>4</sub> (ref. 61)



## Highlight

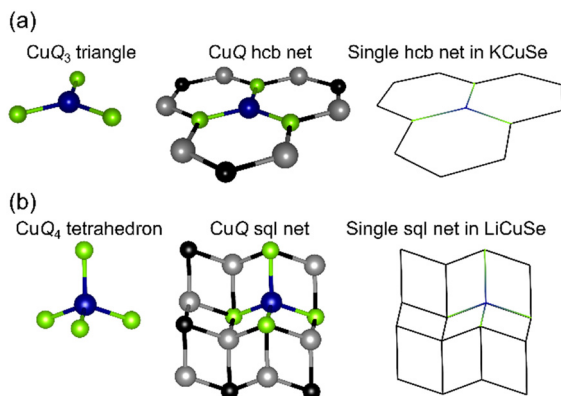


Fig. 2 (a) hcb copper selenide net with trigonal planar Cu coordination in  $\text{KCuSe}$  phase; (b) sql copper selenide net with tetrahedral Cu coordination in  $\text{LiCuSe}$  structure.

between them and forming a slab. For example, the structure of charge balanced trigonal  $\text{CaCu}_2\text{S}_2$  phase is built by connecting some nodes of two **hcb** nets to build  $\text{Cu}_2\text{S}_2^{2-}$  slabs (Fig. 3a–c). Interactions between two flat **hcb** layers change the local environment of both Cu and S atoms, leading to their distorted tetrahedral coordination environment. Ca atoms in this structure also have octahedral sulfur coordination and occupy the interlayer space. Two neighboring **sql** nets with common nodes form a  $\text{Cu}_4\text{S}_3^-$  slab in  $\text{KCu}_4\text{S}_3$  phase (Fig. 3d–f).

The electron deficiency of copper chalcogenide phases can be easily calculated from the chemical composition and the knowledge about Q–Q bonds in the structure (Table 1). For a simple  $\text{NaCuSe}$  case, the total number of valence orbitals is given as a sum of five 3d orbitals from the Cu atoms, one 4s and three 4p orbitals from the Se atoms, resulting in a total of nine. In these orbital count calculations, we assume that Cu 4s and 4p orbitals have significantly higher energy and have only a marginal (yet, very important in some cases) contribution to the top of the valence band. For the electrons, each Cu atom provides 11 electrons, and each S atom offers six electrons, resulting in 17 electrons per (CuS) unit. For



Fig. 3 (a–c) Double hcb and (d–e) double sql slabs in the structures of charge-balanced  $\text{CaCuS}_2$  and charge-unbalanced  $\text{KCu}_4\text{S}_3$  phases, respectively.

$\text{A}^+\text{CuQ}$  phases ( $\text{A} = \text{Li–K}$ ), an additional electron is coming from the alkali metals, charge balancing the layers with one electron to result in nine orbitals with 18 electrons. Doubling the (CuS) units yields 18 orbitals with only 34 electrons, requiring an alkaline earth metal to charge balance it, as in  $\text{BaCu}_2\text{Q}_2$ . On the other hand, if only one alkali cation is balancing the layers in an  $\text{A}^+\text{Cu}_2\text{Q}_2$  composition, such as  $\text{KCu}_2\text{Se}_2$ , the layers are one electron short of the charge balanced state, resulting in a one-electron-deficient structure. Further increase in the number of stacking layers increases the electron deficiency. The copper chalcogenide phases reported to date exhibit a maximum of one electron deficiency per formula unit (or 0.5 electron per single CuS unit in  $\text{NaCu}_2\text{S}_2$ ), allowing one to surmise that the structures with two or more electron deficiency sites per formula unit are unstable. Therefore, ternaries with  $\text{A}^+\text{Cu}_3\text{Q}_3$  stoichiometry have not been reported to date, with  $(\text{CuQ})_3^-$  2D units being likely unstable due to high electron deficiency,  $2/3$  electrons per CuS unit.

It is easy to see that the higher homologues of the  $(\text{CuS})_n$  family should also be unstable. There are, however, ways to alleviate the electron deficiency in compositions with high copper content, by either forming dichalcogenide bonds or sharing atoms between layer units. A good example of the former is  $\text{NaCu}_4\text{Q}_4$  compounds, which formulas can also be written as  $\text{Na}^+[\text{Cu}_4\text{Q}_2(\text{Q}_2)]^-$ . Forming a Q–Q bond effectively eliminates one orbital from the orbital count by shifting Q–Q antibonding state significantly above the Fermi level,<sup>13</sup> resulting in  $9 \times 4 - 1 = 35$  orbitals with  $17 \times 4 + 1 = 69$  electrons. Such units are present in the  $\text{NaCu}_4\text{Q}_4$  phases, which contain a slab of four **hcb** layers with a dichalcogenide bond connecting two inner ones. This dichalcogenide bond binds the layers into a double layer with a kagome dual net topology (Fig. 4, Table 1). The former approach to reducing orbital count achieves the stabilization of the structure by sharing atoms from different layers, typically a chalcogen atom. One common example is  $\text{A}^+(\text{Cu}_4\text{Q}_3)^-$  and  $\text{A}^{2+}(\text{Cu}_4\text{Q}_3)^{2-}$  compositions. In  $\text{A}^+(\text{Cu}_4\text{Q}_3)^-$ ,  $4 \times 5 + 3 \times 4 = 32$  orbitals host  $11 \times 4 + 3 \times 6 + 1 = 63$  electrons, having a deficiency of one hole per formula unit. In the  $\text{ACu}_4\text{Q}_3$  ( $\text{A} = \text{K–Cs}$ ) series of charge unbalanced tetragonal phases,  $\text{Cu}_4\text{Q}_3^-$  slabs are formed by two **sql** nets with shared Q atoms. The slabs are separated by alkali cations in the structures. When a smaller

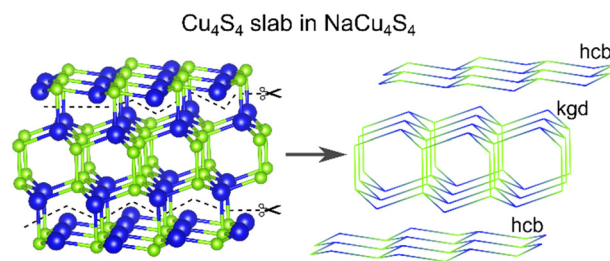


Fig. 4  $\text{Cu}_4\text{S}_4$  slab in the  $\text{NaCu}_4\text{S}_4$  structure made from four hcb layers. Two central layers are connected in kagome dual net motif (kgd).



$\text{Na}^+$  cation occupies the A site, the resulting structure contains vertex-sharing **hcb** layers combined into  $\text{Cu}_4\text{S}_3^-$  slabs. Similar to the  $\text{CaCu}_2\text{S}_2$  phase, the copper coordination number in the  $\text{Cu}_4\text{S}_3^-$  slabs is increased to four and the **hcb** layers are visibly corrugated. The way two inner **hcb** layers of a  $\text{Cu}_4\text{S}_3^-$  slab are connected also matches the topology of kagome dual net. Finally, the highest homologue reported so far has a  $\text{NaCu}_6\text{Se}_4$  composition. In  $\text{NaCu}_6\text{Se}_4$ , two  $\text{CuSe}$  **hcb** nets are divided not by one but by two  $\text{Cu}_2\text{Se}$  double **hcb**, forming slabs with a  $\text{Cu}_6\text{Se}_4$  composition. The formula unit contains 46 orbitals and 91 electrons, showing the same one hole per formula unit electron deficiency. To the best of our knowledge, no ternary phase built on more single and double **hcb** layers has been reported; however, a slab made of two single and three double layers can be found in the structure of  $\text{Cu}_9\text{S}_5$  binary. Overall, shared atoms and dichalcogenide bonds are an efficient way to stabilize higher homologues of copper chalcogenide ternaries, enabling the formation of phases with lower hole concentration per Cu atom. Since higher homologues require using small A:Cu molar ratios, their synthesis may be challenging in the presence of commonly used polychalcogenide fluxes. Alternative synthetic routes using fluxes or solvents that dissolve the starting materials but do not incorporate into the final products are therefore required to stabilize those phases.

The remaining ternary copper sulfide and selenide structures are not based on **hcb** and **sql** nets (Table 2), and their dimensionality varies from 0D to 3D. For example, unlike the  $\text{A}^+(\text{Cu}_4\text{Q}_3)^-$  series, the charge balanced  $\text{Na}_2\text{Cu}_4\text{S}_3$  phase, as well as both the orthorhombic primitive (oP) and base centered (oC) modifications of the  $\text{BaCu}_4\text{S}_3$  phase,

feature complex 2D (Na, oC Ba) and 3D (oP Ba) structures. Another example of isomerism among copper chalcogenide units appears in  $\text{A}_3^+\text{Cu}_4\text{S}_4$  phases ( $\text{A}^+ = \text{Na}^+$  or  $\text{K}^+$ ) containing 1D  $\text{Cu}_4\text{S}_4$  units with decreased dimensionality due to a high content of alkali cations. Besides oP  $\text{BaCu}_4\text{S}_3$ , anionic frameworks can be found in the structures of o- $\text{BaCu}_2\text{Q}_2$ ,  $\text{ACu}_5\text{Q}_3$  (A = Na, Cs), and  $\text{ACu}_7\text{S}_4$  (A = K, Rb) series with alkali and alkaline earth cations occupying channels of frameworks. 2D anionic slabs and layers are quite common among chalcogenides with various stoichiometries. Usually, alkali and alkaline cations separate 2D anionic units, however, in the recently reported  $\text{K}_3\text{BaCu}_7\text{S}_6$  phase  $\text{Ba}^{2+}$  cations are inserted in  $\text{Cu}_7\text{S}_6$  double layers, while  $\text{K}^+$  cations separate such layers.<sup>72</sup> Interstitial sites in copper sulfides and selenides layers are usually vacant. However, in mixed anion  $\text{ACu}_{4.2}\text{TeS}_2$  series of compounds isostructural to  $\text{KCu}_4\text{S}_3$ , there are additional copper atoms partially occupying the voids of the  $\text{CuTeS}_2$  layers.<sup>91</sup> The volume of the Voronoi polyhedron<sup>92</sup> for the interstitial copper atom in the  $\text{KCu}_{4.2}\text{TeS}_2$  structure is about  $3.6 \text{ \AA}^3$  larger than the void in the  $\text{KCu}_4\text{S}_3$  phases. This discrepancy volume is due to the larger size of the Te atom, which allows for the accommodation of additional Cu atoms. High content of cations per formula unit results in chalcogenides dimensionality reduction, while the presence of polychalcogenide anions facilitates the formation of 1D anionic chains: for example,  $\text{CuQ}_4$  and  $\text{CuS}_6$  chains contain  $\text{Q}_4^{2-}$  and  $\text{S}_6^{2-}$  anions, respectively (Table 2). Finally, the charge balanced  $\text{Na}_4\text{Cu}_2\text{S}_3$  phase appears to be the only compound with discrete  $\text{Cu}_2\text{S}_3^{4-}$  0D anions. As can be seen, the complexity of anionic units exceeds structures solely built on **sql** and **hcb** motifs in many chalcogenides.

**Table 2** Ternary copper chalcogenides without **sql** and **hcb** motifs in the structures from highest to lowest Cu : Q ratio in formula unit

Composition	Orbitals count	Electron count	Electron-orbital count mismatch	Type	Dimensionality of $\text{Cu}_x\text{Q}_y$ unit
<b>Cu : Q = 1/6</b>					
$\text{CsCu}((\text{S}_6)^{2-})$ (ref. 93)	58/2 – 10/2	47 + 1	0	Balanced	1D
<b>Cu : Q = 1/4</b>					
$\text{A}^+\text{Cu}(\text{Q}_4^{2-})$ (ref. 77, 94–96)	42/2 – 6/2	35 + 1	0	Balanced	1D
<b>Cu : Q = 8/13</b>					
$\text{Ba}_4\text{Cu}_8\text{Se}_2(\text{Se}_2^{2-})_4(\text{Se}_3^{4-})$ (ref. 97)	184/2 – 10/2	166 + 8	0	Balanced	2D
$\text{Na}_4\text{Cu}_2\text{S}_3$ (ref. 64)	44/2	40 + 4	0	Balanced	0D
<b>Cu : Q = 1</b>					
o- $\text{BaCu}_2\text{Q}_2$ (ref. 73)	36/2	34 + 2	0	Balanced	3D
$\text{KCuS}$ (ref. 65)	18/2	17 + 1	0	Balanced	1D
$\text{A}_3\text{Cu}_4\text{S}_4$ , A = Na, K (ref. 59 and 67)	72/2	68 + 3	1	Unbalanced	1D
<b>Cu : Q = 7/6</b>					
$\text{K}_3\text{BaCu}_7\text{S}_6$ (ref. 72)	118/2	113 + 5	0	Balanced	2D
<b>Cu : Q = 6/5</b>					
$\text{Na}_7\text{Cu}_{12}\text{S}_{10}$ (ref. 58)	200/2	192 + 7	1	Unbalanced	1D
<b>Cu : Q = 5/4</b>					
$\text{Cs}_2\text{Cu}_5\text{Se}_4$ (ref. 69)	82/2	79 + 2	1	Unbalanced	2D
<b>Cu : Q = 4/3</b>					
$\text{BaCu}_4\text{S}_3$ (ref. 98), $\text{Na}_2\text{Cu}_4\text{S}_3$ (ref. 99)	64/2	62 + 2	0	Balanced	3D (Ba), 2D (Na)
$\text{A}_3\text{Cu}_8\text{Q}_6$ , A = K–Cs (ref. 62, 66 and 68)	128/2	124 + 3	1	Unbalanced	2D
$\text{ACu}_3\text{Q}_2$ , A = K–Cs (ref. 70 and 100–102)	46/2	45 + 1	0	Balanced	2D
<b>Cu : Q = 5/3</b>					
$\text{ACu}_5\text{Q}_3$ , A = Na, Cs (ref. 78 and 87–90)	74/2	73 + 1	0	Balanced	3D and 2D
<b>Cu : Q = 7/4</b>					
$\text{ACu}_7\text{S}_4$ , A = K, Rb (ref. 103)	102/2	101 + 1	0	Balanced	3D



## Highlight

Nevertheless, the same principles of orbital and electron count can be applied to them (Table 2). Similar to phases built on CuQ fragments, the electron deficiency in phases without such fragments does not exceed one electron per formula unit.

## Electronic structures of copper chalcogenides

DFT calculations and physical properties measurements of the copper chalcogenide phases can provide a more nuanced view on the electron deficiency than that derived from simple electron count. X-ray photoelectron spectroscopy, bond valence method, and structural data for a series of chalcogenides showed a +1 oxidation state for copper atoms exclusively, implying the formal oxidation states above  $-2$  for chalcogen atoms.<sup>5–7,104–106</sup> This evidence suggests the electron deficit being distributed over chalcogen  $np$  valence orbitals, resulting in the presence of holes on the chalcogenide atoms and ultimately in the metallic p-type conductivity. More detailed electronic structure calculations, however, show that the holes are distributed over bands with Cu 3d and S 3p character, indicating that the positive charge is distributed over both  $\text{Cu}^+$  and  $\text{S}^{2-}$  ions. For example, Fig. 5 shows the results of DFT calculations of electronic band structure and densities of states (DOS) for CuS,<sup>11</sup>  $\text{NaCu}_4\text{S}_3$ ,<sup>13</sup>  $\text{NaCu}_4\text{S}_4$ ,<sup>13</sup> and  $\text{NaCu}_4\text{Se}_4$  (ref. 16) phases.

DFT calculations show crucial common features of all four phases under consideration: first, the upper bands in the band structure cross the Fermi level in the proximity of the  $\Gamma$  point. This accounts for the metallic properties of the chalcogenides and agrees with the experimental data on electrical conductivity and magnetism. Second, the dispersion in the upper bands significantly depends on the direction. Bands contributed by Cu  $3d_{x^2-y^2}$ ,  $3d_{xy}$ , and S  $3p_x$ ,  $3p_y$  orbitals are highly dispersed in directions parallel to  $\text{Cu}_x\text{S}_y$  slabs. This agrees with the structural data, as orbitals forming these bands participate in the copper–chalcogen bonding within the  $\text{Cu}_x\text{S}_y$  slabs. On the contrary, bands with predominant contributions from Cu  $3d_{xz}$  and  $3d_{yz}$  orbitals are weakly dispersed in all directions, as the corresponding orbitals do not participate in the bonding. Notable differences in the band structures of CuS,<sup>9</sup>  $\text{NaCu}_4\text{S}_3$ ,<sup>11</sup>  $\text{NaCu}_4\text{S}_4$ ,<sup>11</sup> and  $\text{NaCu}_4\text{Se}_4$  (ref. 14) phases are observed in the direction perpendicular to the slabs. Cu  $3d_{z^2}$  and Q  $np_z$  orbitals are oriented in this direction. In  $\text{NaCu}_4\text{S}_3$ , the overlap of these orbitals results in the bands crossing the Fermi level and their dispersion in the  $c$  direction in the crystal structure. In CuS,  $\text{NaCu}_4\text{S}_4$  and  $\text{NaCu}_4\text{Se}_4$  Q–Q bonds form, and the overlap of  $np_z$  orbitals significantly surpasses the overlap of  $3d_{z^2}$  and  $np_z$  orbitals. The resulting antibonding band has much higher energy and lies entirely above the Fermi level. DFT calculations confirm strong covalency of the Cu–Q bonds and the metallic nature of the electron deficient chalcogenides. It is important to note that this view



Fig. 5 Electronic band structure and DOS for (a and b) CuS, (c)  $\text{NaCu}_4\text{S}_3$ , (d)  $\text{NaCu}_4\text{S}_4$ , and (e)  $\text{NaCu}_4\text{Se}_4$  phases. Adapted with permission from ref. 11, 13 and 16. Copyright: American Chemical Society.

agrees well with the XPS results, which only show that Cu atoms in a selected structure have the same oxidation state, which is different from the +2 oxidation state. Having a slight hole delocalized over Cu 3d orbitals only marginally increases the formal charge on Cu atoms.

## Conclusions

Ternary copper sulfides and selenides can be divided into two broad groups, charge-balanced and charge unbalanced compounds. The combination of metallic p-type conductivities and covalent bonding makes charge unbalanced phases “covalent metals”. While the compositions of new phases vary significantly, the same square lattice and honeycomb 2D topological motifs persist in the structures of many layered and quasi-layered copper chalcogenides. The metallic nature of charge-unbalanced compounds originates from the presence of holes on the bands with 3d Cu and 3p S character, indicating hole distribution between them. Carrier concentration in the electron deficient phases can be estimated with a simple vacancy count approach, which shows good agreement with



the experimental data. Since copper chalcogenides show a significant variability in their compositions, one can expect that more phases can be discovered when using a reaction mixture with an alkali metal deficit, leading to homologous series with higher Cu content. To date, no phases with  $\text{Cu}_3\text{Q}_3$  stoichiometry of copper chalcogenide units have been reported. While  $\text{Cu}_3\text{Q}_3^-$  slabs are likely unstable due to high electron deficiency, the formation of  $\text{Cu}_3\text{Q}_3^{2-}$  units in the reactions with alkaline earth metals is worth investigating. Overall, electron count can be used to specifically target either metallic or semiconducting phases in the synthesis based on the charge balance. Moreover, conversion of p-type metal into a semiconductor can be done with compositional tuning, as it was demonstrated by charge unbalanced  $\text{CsCu}_4\text{S}_3$  phase transition to charge balanced  $\text{CsCu}_5\text{S}_3$ .

## Data availability

No primary research results, software or code have been included and no new data were generated or analysed as part of this review.

## Author contributions

Sergei A. Novikov: investigation, methodology, validation, writing – original draft, writing – review & editing; James Casey: writing – original draft, writing – review & editing; Hope A. Long: writing – original draft, writing – review & editing; Vladislav V. Klepov: conceptualization, funding acquisition, supervision, investigation, methodology, validation, writing – original draft, writing – review & editing.

## Conflicts of interest

There are no conflicts of interest to report.

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